Octal Buffer/Line Driver with 3-State Outputs

The SN74LS240 and SN74LS244 are Octal Buffers and Line Drivers designed to be employed as memory address drivers, clock drivers and bus-oriented transmitters/receivers which provide improved PC board density.

- Hysteresis at Inputs to Improve Noise Margins
- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Input Clamp Diodes Limit High-Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
VCC	Supply Voltage	4.75	5.0	5.25	V
Τ _Α	Operating Ambient Temperature Range	0	25	70	°C
ЮН	Output Current – High			-3.0	mA
				-15	mA
IOL	Output Current – Low			24	mA



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LOW POWER SCHOTTKY



- WL = Wafer Lot
- YY = Year
- WW = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

LOGIC AND CONNECTION DIAGRAMS DIP (TOP VIEW)





TRUTH TABLES

SN74LS240

INP	OUTPUT	
1G, 2G	001901	
L	L	Н
L	Н	L
Н	Х	(Z)

 $H = HIGH \ Voltage \ Level \\ L = LOW \ Voltage \ Level \\ X = Immaterial \\ Z = HIGH \ Impedance$

SN74LS244

INPU	OUTPUT	
1 G , 2 G		
L	L	L
L	Н	Н
Н	Х	(Z)

http://onsemi.com 2

			Limits					
Symbol	Parameter		Min	Тур	Max	Unit	Test	Conditions
VIH	Input HIGH Voltage		2.0			V	Guaranteed Input All Inputs	HIGH Voltage for
VIL	Input LOW Voltage				0.8	V	Guaranteed Input LOW Voltage for All Inputs	
V _{T+} -V _{T-}	Hysteresis		0.2	0.4		V	$V_{CC} = MIN$	
VIK	Input Clamp Diode Volta	ge		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} =$	–18 mA
Vou			2.4	3.4		V	V _{CC} = MIN, I _{OH} =	= –3.0 mA
⊻ОН	Ouput high voltage		2.0			V	$V_{CC} = MIN, I_{OH} = MAX$	
				0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$
VOL	Output LOW Voltage	Dutput LOW Voltage		0.35	0.5	V	I _{OL} = 24 mA	VIN = VIL or VIH per Truth Table
IOZH	Output Off Current HIGH				20	μΑ	$V_{CC} = MAX, V_{OUT} = 2.7 V$	
IOZL	Output Off Current LOW				-20	μΑ	$V_{CC} = MAX, V_{OUT} = 0.4 V$	
. I					20	μΑ	$V_{CC} = MAX, V_{IN} = 2.7 V$	
ЧН	Input high Current				0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
۱ _{IL}	Input LOW Current				-0.2	mA	$V_{CC} = MAX, V_{IN}$	= 0.4 V
IOS	Output Short Circuit Current (Note 1)		-40		-225	mA	V _{CC} = MAX	
	Power Supply Current Total, Output HIGH				27			
ICC	Total, Output LOW	LS240			44			
	LS Total at HIGH Z LS	LS244			46	mA	V _{CC} = MAX	
		LS240			50			
	LS244				54			

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

1. Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
^t PLH ^t PHL	Propagation Delay, Data to Output LS240		9.0 12	14 18	ns	
^t PLH ^t PHL	Propagation Delay, Data to Output LS244		12 12	18 18	ns	C _L = 45 pF, R _L = 667 Ω
^t PZH	Output Enable Time to HIGH Level		15	23	ns	
^t PZL	Output Enable Time to LOW Level		20	30	ns	
^t PLZ	Output Disable Time from LOW Level		15	25	ns	C _L = 5.0 pF,
^t PHZ	Output Disable Time from HIGH Level		10	18	ns	$\overline{R_L} = 667 \Omega$

AC WAVEFORMS



Figure 1.



Figure 2.





Figure 3.

 V_{E}

 V_{E}

VOUT



SYMBOL	SW1	SW2
^t PZH	Open	Closed
^t PZL	Closed	Open
tPLZ	Closed	Closed
^t PHZ	Closed	Closed

Figure 5.



1.3 V

^tPZH

1.3 V

1.3 V

^tPHZ <u>_</u> ≥VOH _ ≈ 1.3 V

0.5 V

DEVICE ORDERING INFORMATION

Device Order Number	Package Type	Tape and Reel Size
SN74LS240N	240N PDIP–20	
SN74LS240DW	SOIC-WIDE	38 Units/Rail
SN74LS240DWR2	SOIC-WIDE	2500/Tape and Reel
SN74LS240M	SOEIAJ-20	See Note 2
SN74LS240MEL	SOEIAJ-20	See Note 2
SN74LS244N	PDIP-20	1440 Units/Box
SN74LS244DW	SOIC-WIDE	38 Units/Rail
SN74LS244DWR2	SOIC-WIDE	2500/Tape and Reel
SN74LS244M	SOEIAJ-20	See Note 2
SN74LS244MEL	SOEIAJ-20	See Note 2

2. For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

PACKAGE DIMENSIONS



D SUFFIX PLASTIC SOIC PACKAGE CASE 751D-05 **ISSUE F**



NOTES:

- I. DIMENSIONS ARE IN MILLIMETERS.
 INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD

4.57

15°

1.01

- PROTRUSION. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- 4 5.
- MAXIMUM MOLD FRO INDIANO (1.5 PER SIDE) DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS			
DIM	MIN	MAX		
Α	2.35	2.65		
A1	0.10	0.25		
В	0.35	0.49		
С	0.23	0.32		
D	12.65	12.95		
Е	7.40	7.60		
е	1.27	BSC		
Н	10.05	10.55		
h	0.25	0.75		
L	0.50	0.90		
θ	0 °	7 °		

PACKAGE DIMENSIONS

M SUFFIX SOEIAJ PACKAGE CASE 967-01 ISSUE O





DETAIL P





NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) OFD CIDC 2. 3.
- 4.
- PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR COATED ON THE LOWER 5. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α		2.05		0.081	
A ₁	0.05	0.20	0.002	0.008	
b	0.35	0.50	0.014	0.020	
C	0.18	0.27	0.007	0.011	
D	12.35	12.80	0.486	0.504	
E	5.10	5.45	0.201	0.215	
е	1.27	BSC	0.050 BSC		
HE	7.40	8.20	0.291	0.323	
Г	0.50	0.85	0.020	0.033	
٦F	1.10	1.50	0.043	0.059	
M	0 °	10 °	0 °	10 °	
Q ₁	0.70	0.90	0.028	0.035	
Z		0.81		0.032	

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